

HT2050 Five LAMP/LED Flash Driver

Features

- C-MOS Metal-Gate Process
- Operating voltage: 1.2V~4.5V
- Low stand-by current: 1μA at 3V
- A five lamp flash driver
- Random or sequence flash

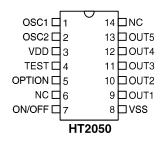
- On/Off toggle control
- 1/10 duty cycle output
- A built-in oscillator
- Minimum external components

General Description

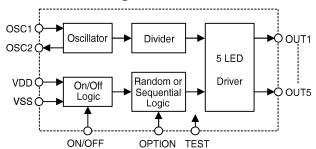
The HT2050 is a low cost, low-power CMOS fabricated LSI chip designed for lamp and LED flash drivers. It contains five flash outputs. Each flash output is with a 10mA capability that can implement random or sequential flash-

ing controlled by a single option pin. The chip requires only one external resistor for normal applications. It is very suitable for use in products that require flashing lights, such as gift cards, Christmas decoration, etc.

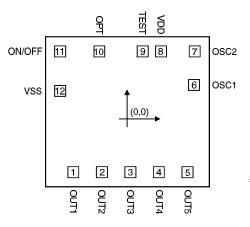
Pin Assignment



Block Diagram



Pad Coordinates



Unit: mil

Pad No.	X	Y	Pad No.	X	Y	
1	-21.09	-20.9	7	26.55	26.5	
2	-9.89	-20.9	8	13.35	26.5	
3	1.31	-20.9	9	6.15	26.5	
4	12.51	-20.9	10	-10.89	26.5	
5	23.71	-20.9	11	-26.25	26.5	
6	26.23	13.3	12	-26.25	10.98	

Chip size: $64 \times 59 \text{ (mil)}^2$

1

^{*} The IC substrate should be connected to VDD in the PCB layout artwork.



Pad Description

Pad No.	Pad Name	I/O	Description	
1	OUT1	О	Lamp/LED flash drive output	
2	OUT2	О	Lamp/LED flash drive output	
3	OUT3	О	Lamp/LED flash drive output	
4	OUT4	О	Lamp/LED flash drive output	
5	OUT5	О	Lamp/LED flash drive output	
6	OSC1	I	Oscillator input	
7	OSC2	О	Oscillator output	
8	VDD	I	Positive power supply	
9	TEST	I/O	For IC test only	
10	OPTION	I	Random or sequence function selection	
11	ON/OFF	I	Toggle ON/OFF control	
12	VSS	I	Negative power supply, GND	

Note: OPTION=VDD \rightarrow Sequential Mode OPTION=Open \rightarrow Random Mode

Absolute Maximum Ratings

Supply Voltage0.3V to 5V	Storage Temperature50°C to 125°C
Input/Output Voltage V _{SS} -0.3V to V _{DD} +0.3V	Operating Temperature0°C to 70°C

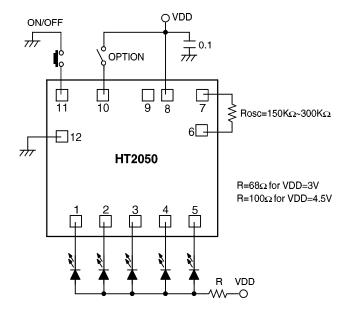
Electrical Characteristics

Symbol	Parameter	Test Condition		M:	Т	Mari	T 1 *4
	Parameter	V _{DD}	Condition	Min.	Тур.	Max.	Unit
V_{DD}	Operating Voltage		_	1.2	3	4.5	V
ISTB	Stand-by Current	3V	_	_	1	2	μΑ
I_{DD}	Operating Current	3V	No load	_	200	500	μΑ
IoL	Outnot Sink Coment	1.5V	V _{OL} =0.5V	5	8	_	mA
	Output Sink Current	3V	V _{OL} =0.5V	10	15	_	mA
Fosc	Oscillator Frequency	_	R=150K~300KΩ	_	64K	_	Hz

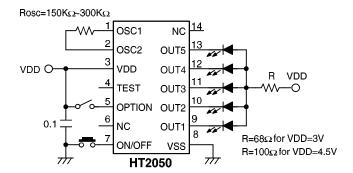
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Application Circuit



* The IC substrate should be connected to VDD in PCB layout artwork.



3 26th Mar '97